Differential Receiver

The MC10EP16 is a differential receiver. The device is functionally equivalent to the EL16 and LVEL16 devices with higher performance capabilities. With output transition times significantly faster than the EL16 and LVEL16, the EP16 is ideally suited for interfacing with high frequency sources.

The EP16 provides a V_{BB} output for either single-ended use or as a DC bias for AC coupling to the device within the package. The V_{BB} pin should be used only as a bias for the EP16 as its current sink/source capability is limited. Whenever used, the V_{BB} pin should be bypassed to ground via a $0.01\mu f$ capacitor.

- 160ps Propagation Delay
- High Bandwidth to 3 GHz Typical
- PECL mode: 3.0V to 5.5V V_{CC} with $V_{EE} = 0V$
- ECL mode: 0V V_{CC} with $V_{EE} = -3.0V$ to -5.5V
- Internal Input Resistors: Pulldown on D, Pulldown and Pullup on \overline{D}
- Q Output will default LOW with inputs open or at VEE
- ESD Protection: 4KV HBM, 200V MM
- V_{BB} Output
- New Differential Input Common Mode Range
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
 For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count: 167 devices

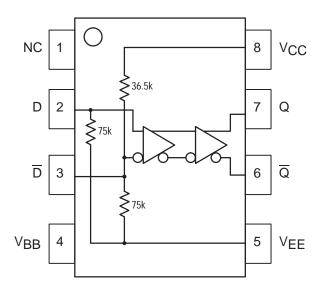


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



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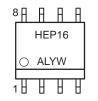
Formerly a Division of Motorola

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SO-8 D SUFFIX CASE 751

MARKING DIAGRAM



A = Assembly Location

L = Wafer Lot Y = Year W = Work Week

*For additional information, see Application Note AND8002/D

| PIN DESCRIPTION | | | | | | | |
|------------------------------|---------------------|--|--|--|--|--|--|
| PIN FUNCTION | | | | | | | |
| D, $\overline{\overline{D}}$ | ECL Data Inputs | | | | | | |
| Q, $\overline{\mathbb{Q}}$ | ECL Data Outputs | | | | | | |
| V _{BB} | Ref. Voltage Output | | | | | | |

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|---------|------------------|
| MC10EP16D | SOIC | 98 Units/Rail |
| MC10EP16DR2 | SOIC | 2500 Tape & Reel |

MAXIMUM RATINGS*

| Symbol | Parameter | Value | Unit |
|------------------|---------------------------------------------------------------------------|---------------|------|
| VEE | Power Supply (V _{CC} = 0V) | -6.0 to 0 | VDC |
| Vcc | Power Supply (V _{EE} = 0V) | 6.0 to 0 | VDC |
| VI | Input Voltage ($V_{CC} = 0V$, V_I not more negative than V_{EE}) | -6.0 to 0 | VDC |
| VI | Input Voltage ($V_{EE} = 0V$, V_{I} not more positive than V_{CC}) | 6.0 to 0 | VDC |
| lout | Output Current Continuous Surge | | mA |
| I _{BB} | V _{BB} Sink/Source Current† | ± 0.5 | mA |
| TA | Operating Temperature Range | -40 to +85 | °C |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| θЈΑ | Thermal Resistance (Junction–to–Ambient) Still Air 500lfpm | | °C/W |
| θJC | Thermal Resistance (Junction-to-Case) | 41 to 44 ± 5% | °C/W |
| T _{sol} | Solder Temperature (<2 to 3 Seconds: 245°C desired) | 265 | °C |

^{*} Maximum Ratings are those values beyond which damage to the device may occur.

DC CHARACTERISTICS, ECL/LVECL ($V_{CC} = 0V$; $V_{EE} = -5.5V$ to -3.0V) (Note 4.)

| | | | –40°C | | 25°C | | | | | | |
|-----------------|---------------------------------------------------|-------------|-------|-------|-------------|-------|-------|-------------|-------|-------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| IEE | Power Supply Current (Note 1.) | 20 | 24 | 31 | 20 | 24 | 31 | 20 | 24 | 32 | mA |
| VOH | Output HIGH Voltage (Note 2.) | -1135 | -1060 | -885 | -1070 | -945 | -820 | -1010 | -885 | -760 | mV |
| VOL | Output LOW Voltage (Note 2.) | -1935 | -1810 | -1685 | -1870 | -1745 | -1620 | -1810 | -1685 | -1560 | mV |
| VIH | Input HIGH Voltage Single Ended | -1210 | | -885 | -1145 | | -820 | -1085 | | -760 | mV |
| VIL | Input LOW Voltage Single Ended | -1935 | | -1610 | -1870 | | -1545 | -1810 | | -1485 | mV |
| V _{BB} | Output Voltage Reference | -1510 | -1410 | -1310 | -1445 | -1345 | -1245 | -1385 | -1285 | -1185 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Note 3.) | VEE | +2.0 | 0.0 | VEE | +2.0 | 0.0 | VEE | +2.0 | 0.0 | V |
| l _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μΑ |
| IIL | Input LOW Current DD | 0.5 -150 | | | 0.5 -150 | | | 0.5 -150 | | | μΑ |

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- V_{CC} = 0V, V_{EE} = V_{EEmin} to V_{EEmax}, all other pins floating.
 All loading with 50 ohms to V_{CC}-2.0 volts.
 V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.
 Input and output parameters vary 1:1 with V_{CC}.

[†] Use for inputs of same package only.

DC CHARACTERISTICS, LVPECL ($V_{CC} = 3.3V \pm 0.3V$, $V_{EE} = 0V$) (Note 8.)

| | | | –40°C | | | 25°C | | | | | |
|-----------------|------------------------------------------------|-------------|-------|------|-------------|------|------|-------------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| IEE | Power Supply Current (Note 5.) | 20 | 24 | 31 | 20 | 24 | 31 | 20 | 24 | 32 | mA |
| VOH | Output HIGH Voltage (Note 6.) | 2165 | 2240 | 2415 | 2230 | 2355 | 2480 | 2290 | 2415 | 2540 | mV |
| VOL | Output LOW Voltage (Note 6.) | 1365 | 1490 | 1615 | 1430 | 1555 | 1680 | 1490 | 1615 | 1740 | mV |
| VIH | Input HIGH Voltage Single Ended | 2090 | | 2415 | 2155 | | 2480 | 2215 | | 2540 | mV |
| V _{IL} | Input LOW Voltage Single Ended | 1365 | | 1690 | 1430 | | 1755 | 1490 | | 1815 | mV |
| V_{BB} | Output Voltage Reference | 1790 | 1890 | 1990 | 1855 | 1955 | 2055 | 1915 | 2015 | 2115 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Note 7.) | 2.0 | | 3.3 | 2.0 | | 3.3 | 2.0 | | 3.3 | V |
| lн | Input HIGH Current | | | 150 | | | 150 | | | 150 | μΑ |
| IIL | Input LOW Current D D | 0.5 -150 | | | 0.5 -150 | | | 0.5 -150 | | | μА |

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 5. $V_{CC} = 3.0V$, $V_{EE} = 0V$, all other pins floating. 6. All loading with 50 ohms to V_{CC} -2.0 volts.
- V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.
 Input and output parameters vary 1:1 with V_{CC}.

DC CHARACTERISTICS, PECL ($V_{CC} = 5.0V \pm 0.5V$, $V_{EE} = 0V$) (Note 12.)

| | | | –40°C | | | 25°C | | | | | |
|-----------------|-------------------------------------------------|-------------|-------|------|-------------|------|------|-------------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| IEE | Power Supply Current (Note 9.) | 20 | 24 | 31 | 20 | 24 | 31 | 20 | 24 | 32 | mA |
| Vон | Output HIGH Voltage (Note 10.) | 3865 | 3940 | 4115 | 3930 | 4055 | 4180 | 3990 | 4115 | 4240 | mV |
| VOL | Output LOW Voltage (Note 10.) | 3065 | 3190 | 3315 | 3130 | 3255 | 3380 | 3190 | 3315 | 3440 | mV |
| VIH | Input HIGH Voltage Single Ended | 3790 | | 4115 | 3855 | | 4180 | 3915 | | 4240 | mV |
| VIL | Input LOW Voltage Single Ended | 3065 | | 3390 | 3130 | | 3455 | 3190 | | 3515 | mV |
| V _{BB} | Output Voltage Reference | 3490 | 3590 | 3690 | 3555 | 3655 | 3755 | 3615 | 3715 | 3815 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Note 11.) | 2.0 | | 5.0 | 2.0 | | 5.0 | 2.0 | | 5.0 | ٧ |
| lН | Input HIGH Current | | | 150 | | | 150 | | | 150 | μΑ |
| I _{IL} | Input LOW Current D D | 0.5 -150 | | | 0.5 -150 | | | 0.5 -150 | | | μΑ |

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

^{9.} V_{CC} = 5.0V, V_{EE} = 0V, all other pins floating.

10. All loading with 50 ohms to V_{CC}-2.0 volts.

11. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.

12. Input and output parameters vary 1:1 with V_{CC}.

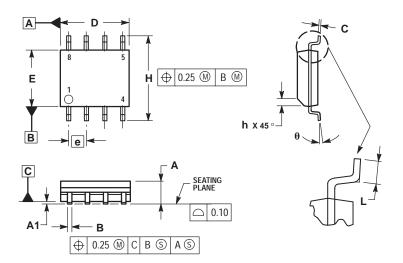
AC CHARACTERISTICS ($V_{CC} = 0V$; $V_{EE} = -3.0V$ to -5.5V) or ($V_{CC} = 3.0V$ to 5.5V; $V_{EE} = 0V$)

| | | | | | | 22 - 31) | | | | | |
|---------------------|---------------------------------------------|-----|-------|------|-----|----------|------|-----|------|------|------|
| | | | –40°C | | | 25°C | | | 85°C | | |
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| fmax | Maximum Toggle Frequency (Note 13.) | | 3.0 | | | 3.0 | | | 3.0 | | GHz |
| tpLH, tpHL | Propagation Delay to Output Differential | 100 | 160 | 240 | 100 | 160 | 240 | 120 | 190 | 280 | ps |
| tSKEW | Duty Cycle Skew (Note 14.) | | 5.0 | | | 5.0 | 20 | | 5.0 | 20 | ps |
| ^t JITTER | Cycle-to-Cycle Jitter | | TBD | | | TBD | | | TBD | | ps |
| V_{PP} | Input Voltage Swing (Diff.) | 150 | 800 | 1200 | 150 | 800 | 1200 | 150 | 800 | 1200 | mV |
| t _r | Output Rise/Fall Times Q (20% – 80%) | 70 | 120 | 170 | 80 | 130 | 180 | 100 | 150 | 200 | ps |

^{13.} F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.
14. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

PACKAGE DIMENSIONS

SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. DIMENSIONS ARE IN MILLIMETER.
 3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIMETERS | | | | | | | | | |
|-----|-------------|------|--|--|--|--|--|--|--|--|
| DIM | MIN | MAX | | | | | | | | |
| Α | 1.35 | 1.75 | | | | | | | | |
| A1 | 0.10 | 0.25 | | | | | | | | |
| В | 0.35 | 0.49 | | | | | | | | |
| С | 0.19 | 0.25 | | | | | | | | |
| D | 4.80 | 5.00 | | | | | | | | |
| Ε | 3.80 | 4.00 | | | | | | | | |
| е | 1.27 | BSC | | | | | | | | |
| Н | 5.80 | 6.20 | | | | | | | | |
| h | 0.25 | 0.50 | | | | | | | | |
| L | 0.40 | 1.25 | | | | | | | | |
| θ | 0° | 7 ° | | | | | | | | |

Notes

Notes

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